

UNR521x Series (UN521x Series)

Silicon NPN epitaxial planar type

For digital circuits

■ Features

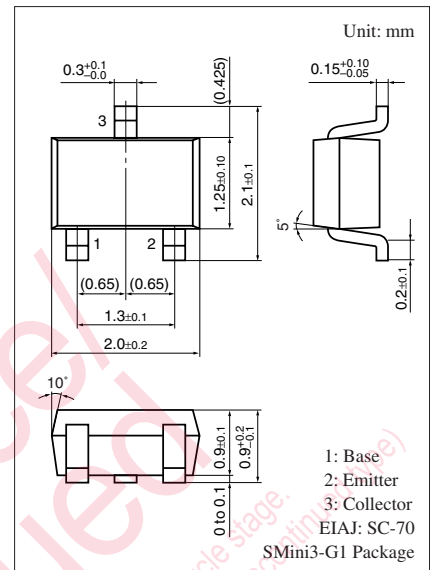
- Costs can be reduced through downsizing of the equipment and reduction of the number of parts
- S-Mini type package, allowing automatic insertion through the tape packing and magazine packing

■ Resistance by Part Number

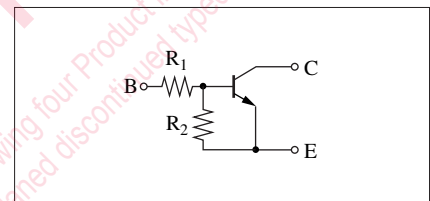
		Marking symbol (R ₁)		(R ₂)
• UNR5210	(UN5210)	8L	47 kΩ	—
• UNR5211	(UN5211)	8A	10 kΩ	10 kΩ
• UNR5212	(UN5212)	8B	22 kΩ	22 kΩ
• UNR5213	(UN5213)	8C	47 kΩ	47 kΩ
• UNR5214	(UN5214)	8D	10 kΩ	47 kΩ
• UNR5215	(UN5215)	8E	10 kΩ	—
• UNR5216	(UN5216)	8F	4.7 kΩ	—
• UNR5217	(UN5117)	8H	22 kΩ	—
• UNR5218	(UN5218)	8I	0.51 kΩ	5.1 kΩ
• UNR5219	(UN5219)	8K	1 kΩ	10 kΩ
• UNR521D	(UN521D)	8M	47 kΩ	10 kΩ
• UNR521E	(UN521E)	8N	47 kΩ	22 kΩ
• UNR521F	(UN521F)	8O	4.7 kΩ	10 kΩ
• UNR521K	(UN521K)	8P	10 kΩ	4.7 kΩ
• UNR521L	(UN521L)	8Q	4.7 kΩ	4.7 kΩ
• UNR521M	(UN521M)	EL	2.2 kΩ	47 kΩ
• UNR521N	(UN521N)	EX	4.7 kΩ	47 kΩ
• UNR521T	(UN521T)	EZ	22 kΩ	47 kΩ
• UNR521V	(UN521V)	FD	2.2 kΩ	2.2 kΩ
• UNR521Z	(UN521Z)	FF	4.7 kΩ	22 kΩ

■ Absolute Maximum Ratings T_a = 25°C

Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	V _{CBO}	50	V
Collector-emitter voltage (Base open)	V _{CEO}	50	V
Collector current	I _C	100	mA
Total power dissipation	P _T	150	mW
Junction temperature	T _J	150	°C
Storage temperature	T _{stg}	-55 to +150	°C



Internal Connection



Note) The part numbers in the parenthesis show conventional part number.

■ Electrical Characteristics $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

Parameter		Symbol	Conditions	Min	Typ	Max	Unit
Collector-base voltage (Emitter open)		V_{CBO}	$I_C = 10 \mu\text{A}, I_E = 0$	50			V
Collector-emitter voltage (Base open)		V_{CEO}	$I_C = 2 \text{ mA}, I_B = 0$	50			V
Collector-base cutoff current (Emitter open)		I_{CBO}	$V_{CB} = 50 \text{ V}, I_E = 0$			0.1	μA
Collector-emitter cutoff current (Base open)		I_{CEO}	$V_{CE} = 50 \text{ V}, I_B = 0$			0.5	
Emitter-base cutoff current (Collector open)	UNR5210/5215/5216/5217	I_{EBO}	$V_{EB} = 6 \text{ V}, I_C = 0$			0.01	mA
	UNR5213					0.1	
	UNR5212/5214/521D/ 521E/521M/521N/521T					0.2	
	UNR521Z					0.4	
	UNR5211					0.5	
	UNR521F/521K					1.0	
	UNR5219					1.5	
	UNR5218/521L/521V					2.0	
Forward current transfer ratio	UNR521V	h_{FE}	$V_{CE} = 10 \text{ V}, I_C = 5 \text{ mA}$	6		20	—
	UNR5218/521K/521L			20			
	UNR5219/521D/521F			30			
	UNR5211			35			
	UNR5212/521E			60			
	UNR521Z			60	200		
	UNR5213/5214/521M			80			
	UNR521N/521T			80	400		
	UNR5210*/5215*/5216*/5217*			160	460		
Collector-emitter saturation voltage		$V_{CE(sat)}$	$I_C = 10 \text{ mA}, I_B = 0.3 \text{ mA}$			0.25	V
UNR521V				$I_C = 10 \text{ mA}, I_B = 1.5 \text{ mA}$			
Output voltage high-level		V_{OH}	$V_{CC} = 5 \text{ V}, V_B = 0.5 \text{ V}, R_L = 1 \text{ k}\Omega$	4.9			V
Output voltage low-level		V_{OL}	$V_{CC} = 5 \text{ V}, V_B = 2.5 \text{ V}, R_L = 1 \text{ k}\Omega$			0.2	V
UNR5213/521K			$V_{CC} = 5 \text{ V}, V_B = 3.5 \text{ V}, R_L = 1 \text{ k}\Omega$				
UNR521D			$V_{CC} = 5 \text{ V}, V_B = 10 \text{ V}, R_L = 1 \text{ k}\Omega$				
UNR521E			$V_{CC} = 5 \text{ V}, V_B = 6.0 \text{ V}, R_L = 1 \text{ k}\Omega$				
Transition frequency		f_T	$V_{CB} = 10 \text{ V}, I_E = -2 \text{ mA}, f = 200 \text{ MHz}$		150		MHz
Input resistance	UNR5218	R_1		-30%	0.51	+30%	$\text{k}\Omega$
	UNR5219				1.0		
	UNR521M/521V				2.2		
	UNR5216/521F/521L/521N UNR521Z				4.7		
	UNR5211/5214/5215/521K				10		
	UNR5212/5217/521T				22		
	UNR5210/5213/521D/521E				47		

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

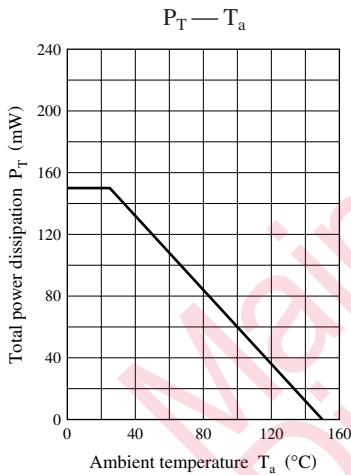
2. *: Rank classification

Rank	Q	R	S	No-rank
h_{FE}	160 to 260	210 to 340	290 to 460	160 to 460

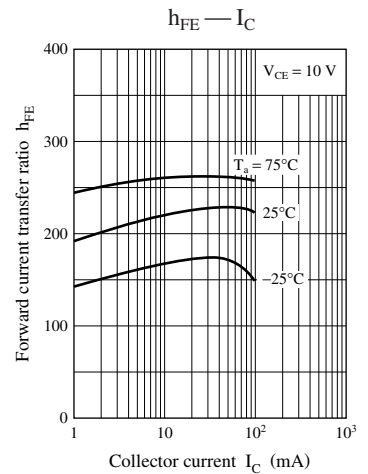
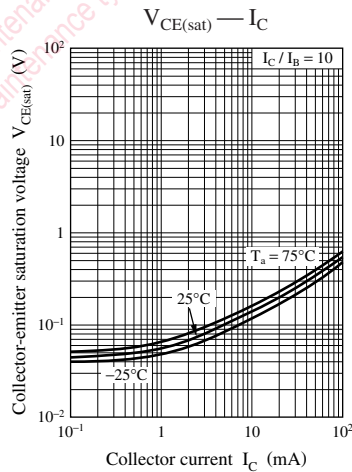
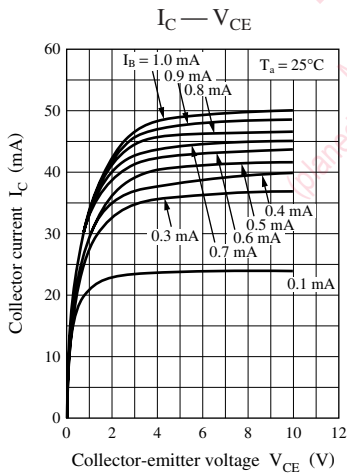
■ Electrical Characteristics (continued) $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

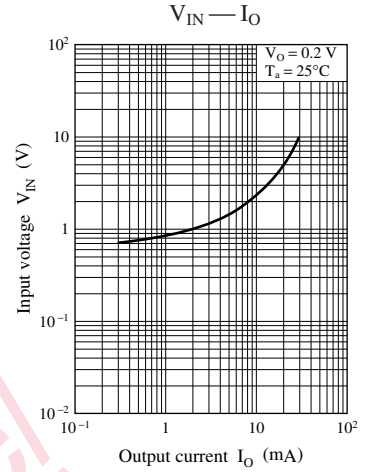
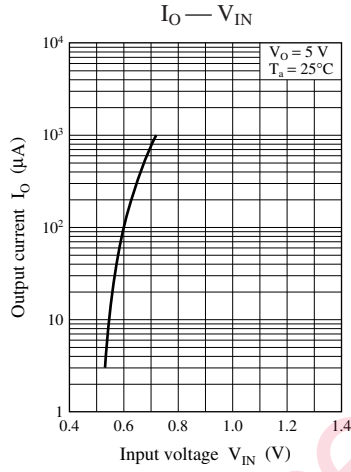
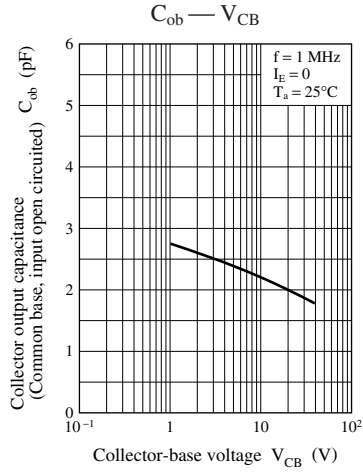
	Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Resistance ratio	UNR521M	R_1/R_2			0.047		—
	UNR521N				0.1		
	UNR5218/5219				0.08	0.10	0.12
	UNR521Z					0.21	
	UNR5214				0.17	0.21	0.25
	UNR521T					0.47	
	UNR521F				0.37	0.47	0.57
	UNR521V					1.0	
	UNR5211/5212/5213/521L				0.8	1.0	1.2
	UNR521K				1.70	2.13	2.60
	UNR521E				1.70	2.14	2.60
UNR521D		3.7	4.7	5.7			

Common characteristics chart

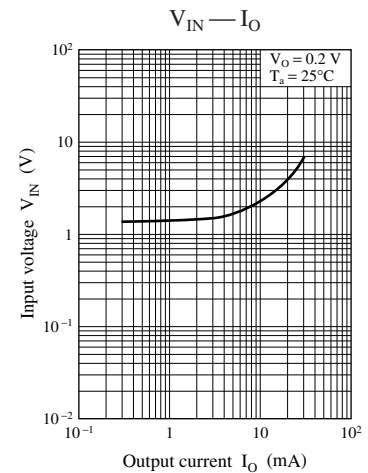
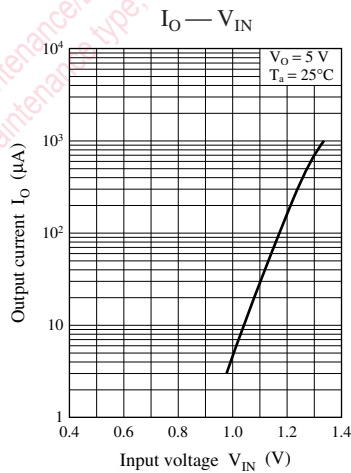
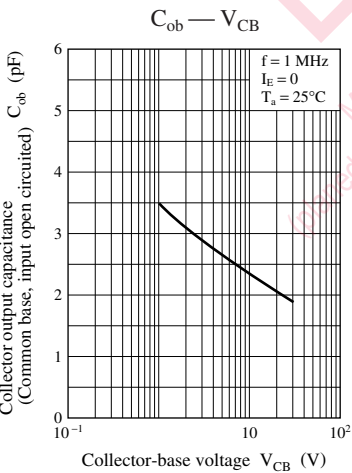
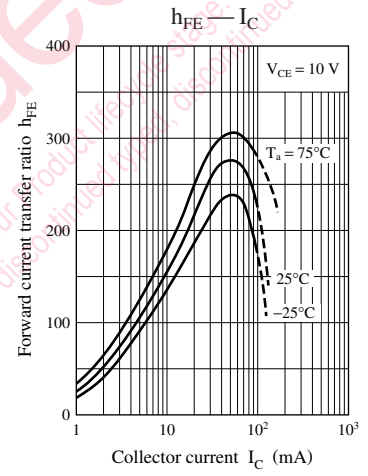
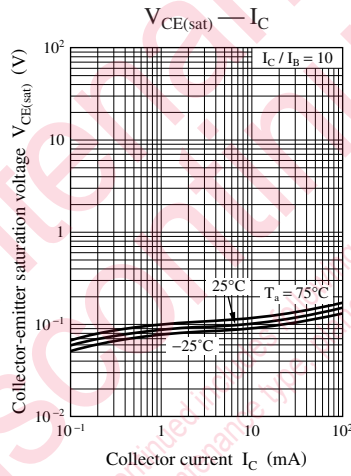
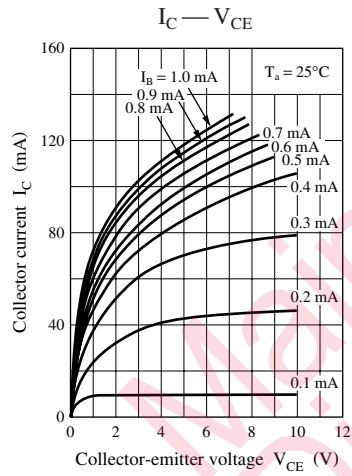


Characteristics charts of UNR5210

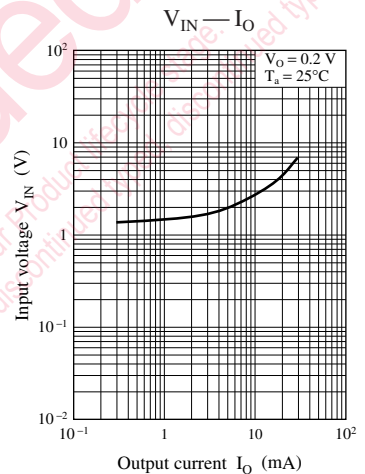
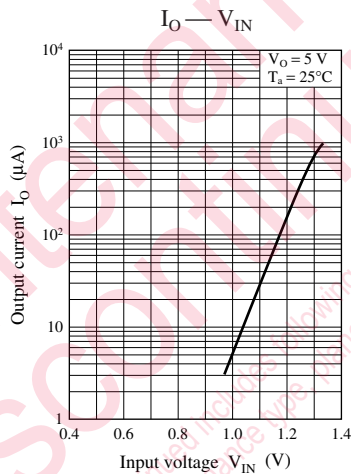
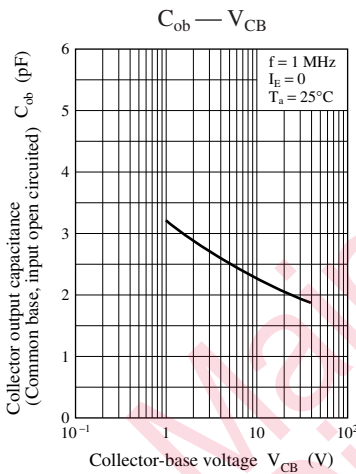
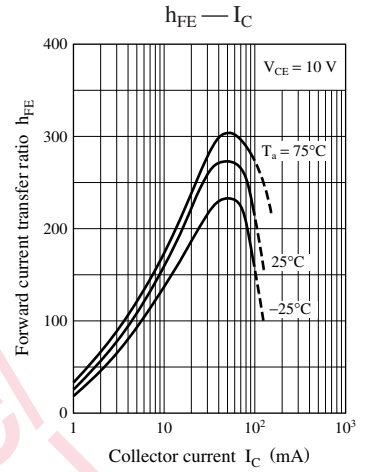
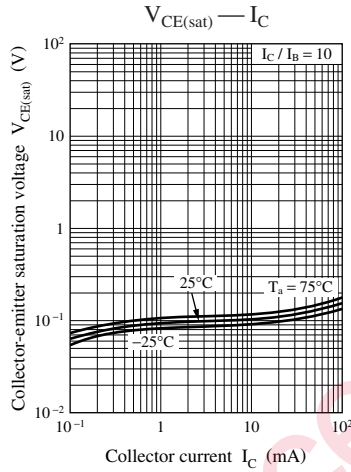
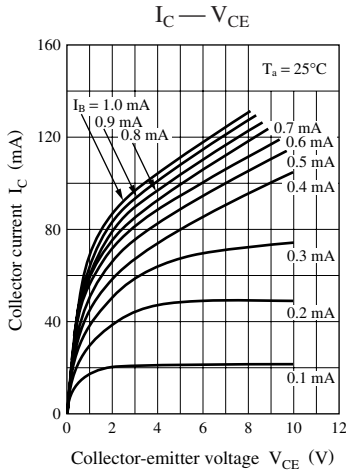




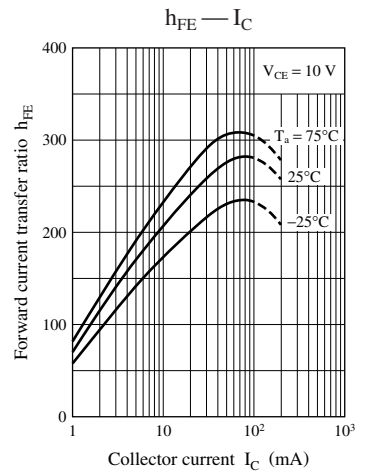
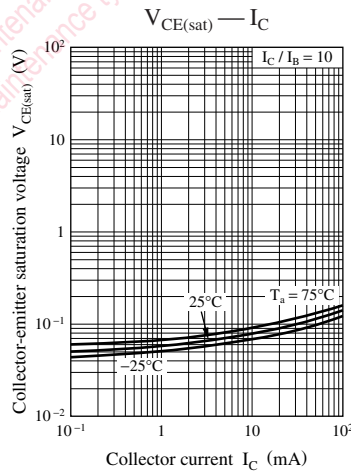
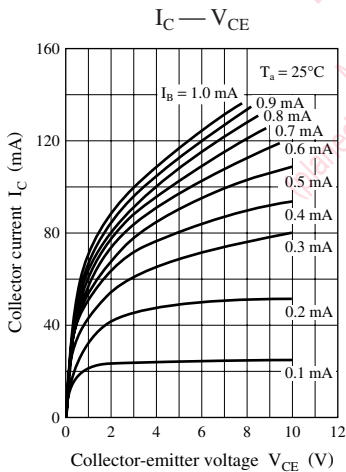
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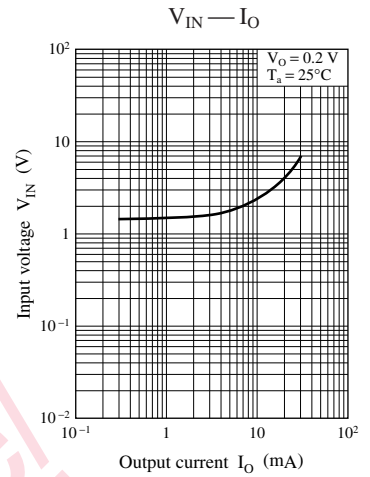
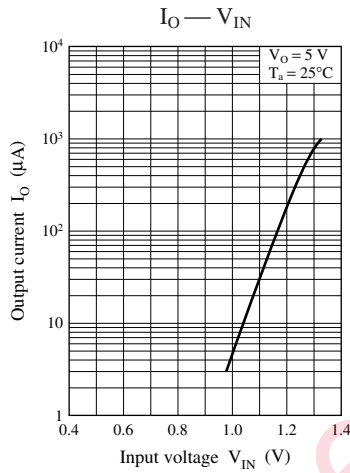
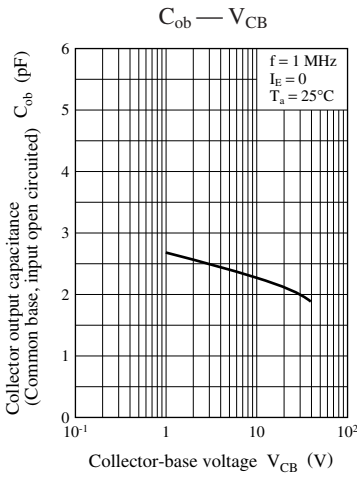


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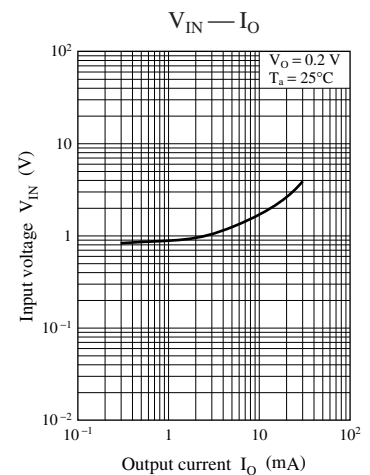
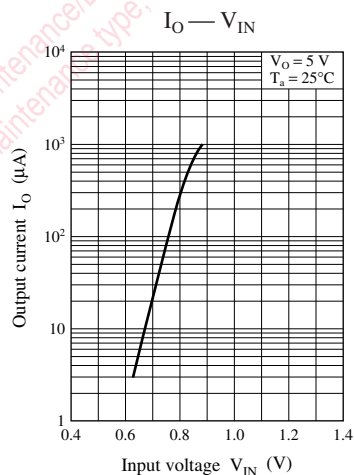
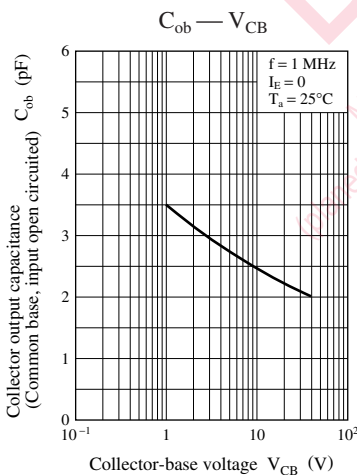
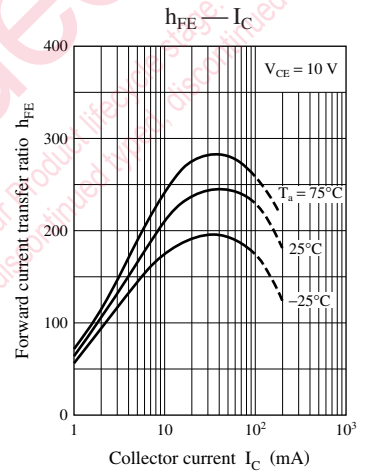
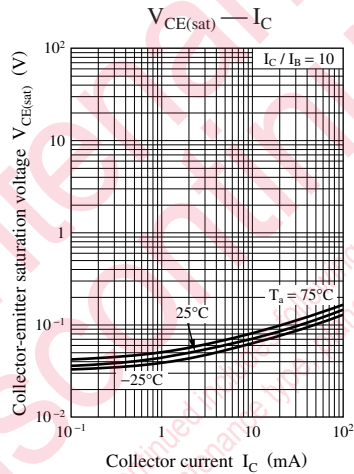
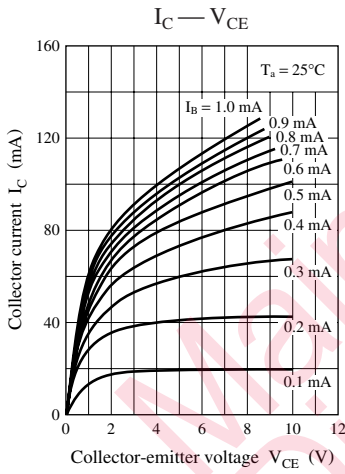


Characteristics charts of UNR5213

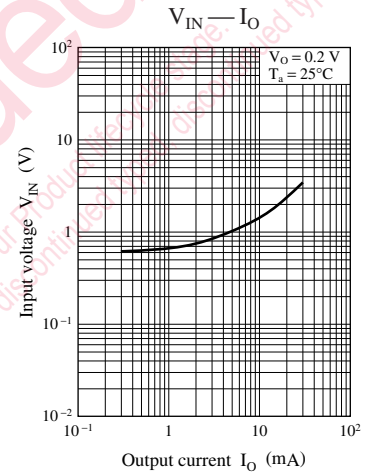
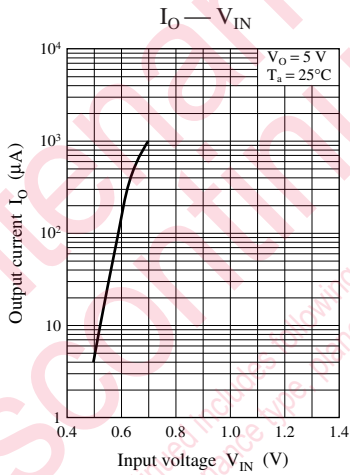
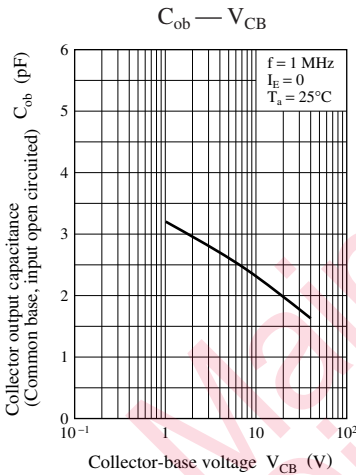
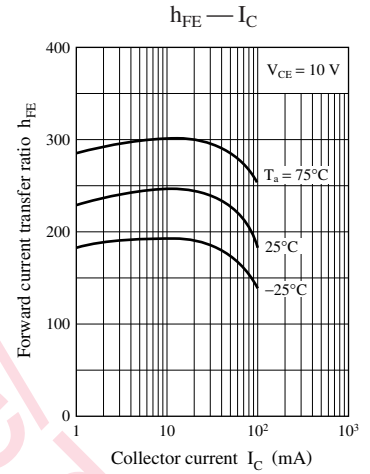
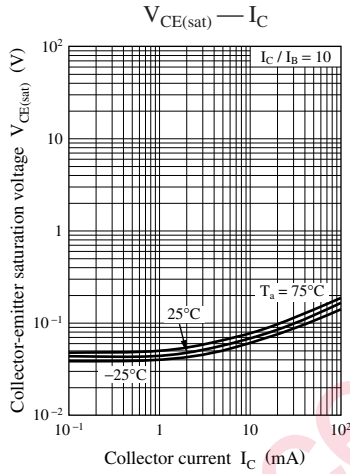
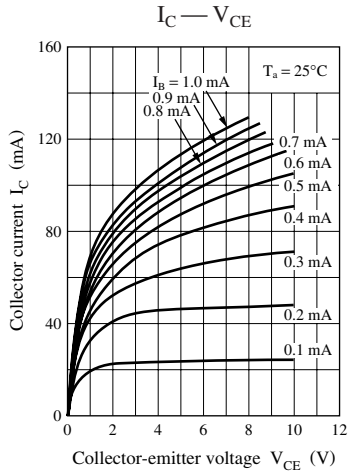




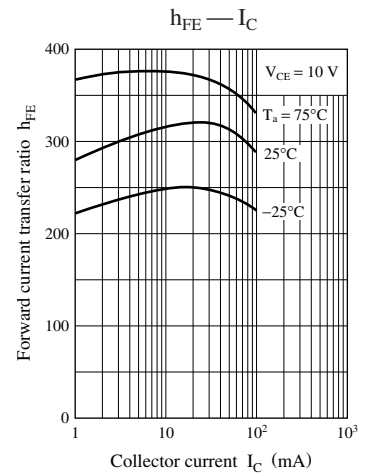
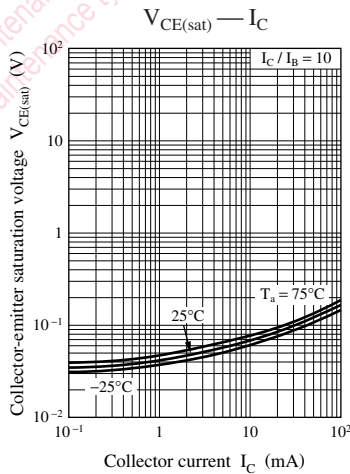
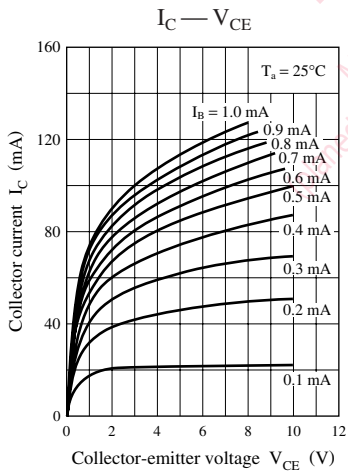
Characteristics charts of UNR5214

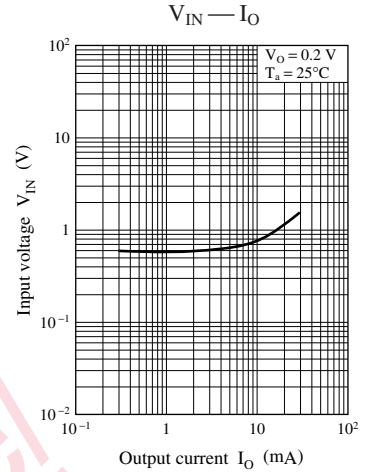
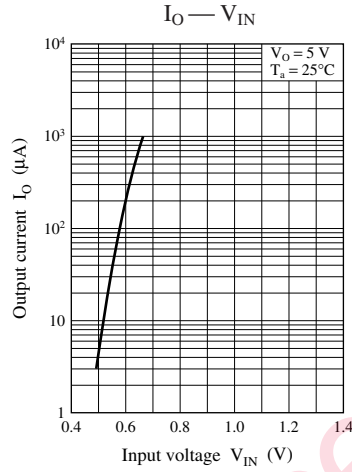
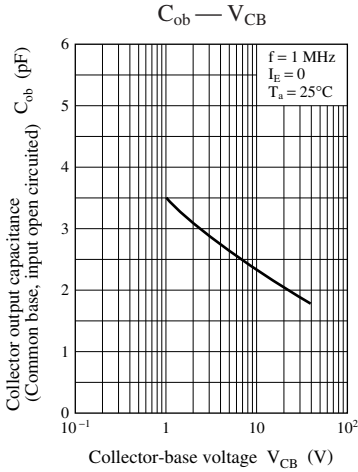


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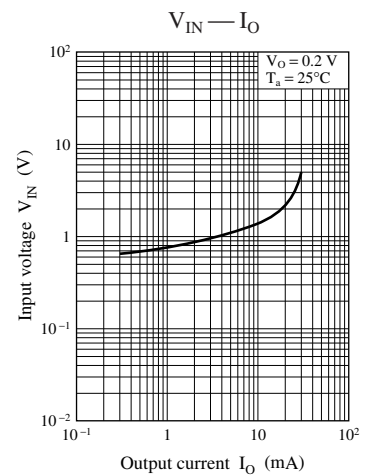
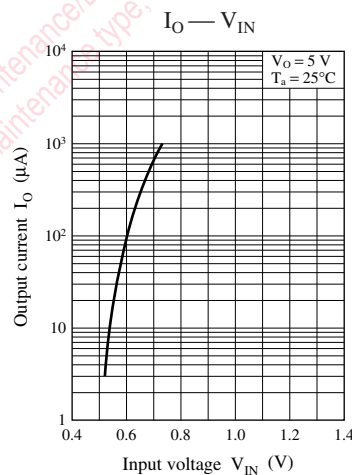
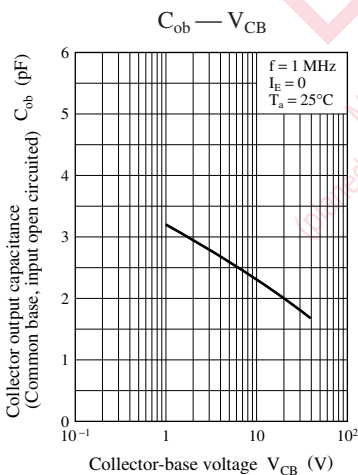
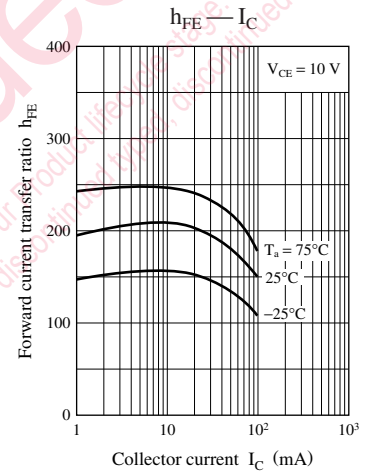
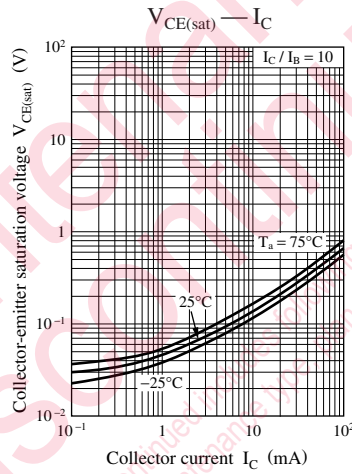
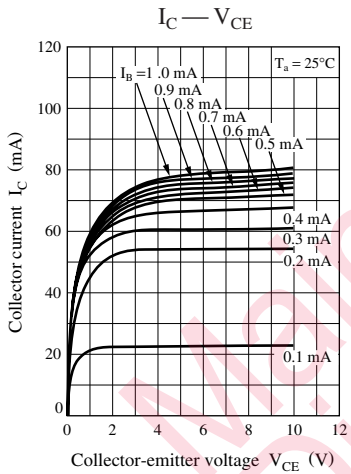


Characteristics charts of UNR5216

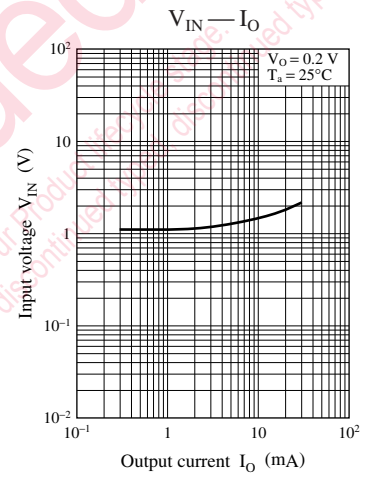
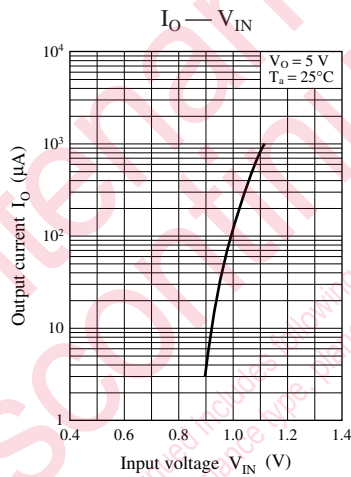
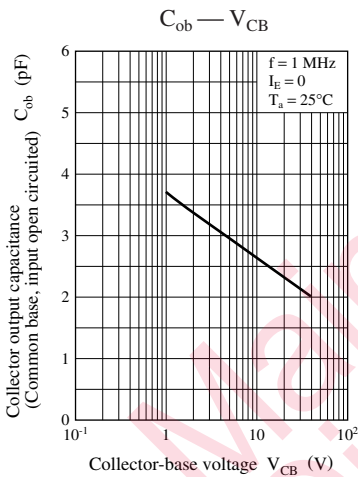
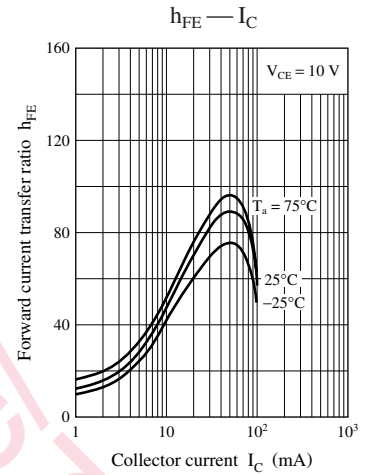
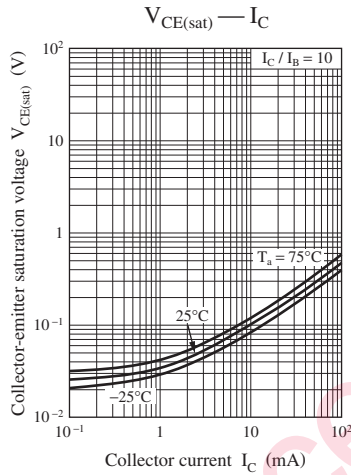
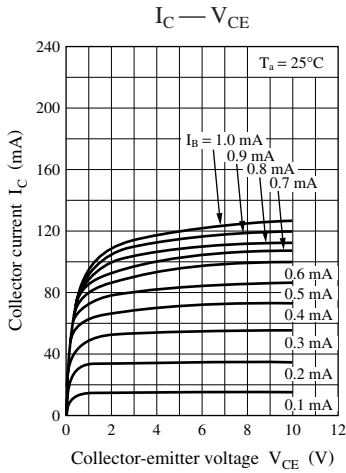




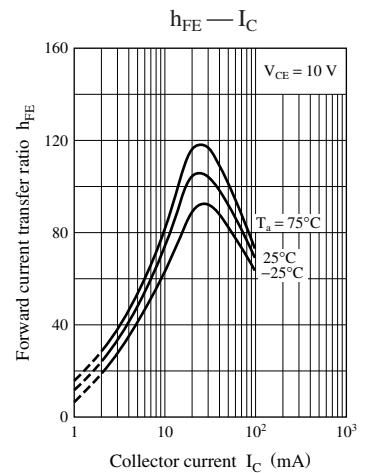
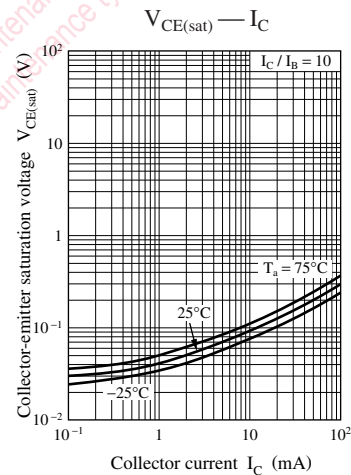
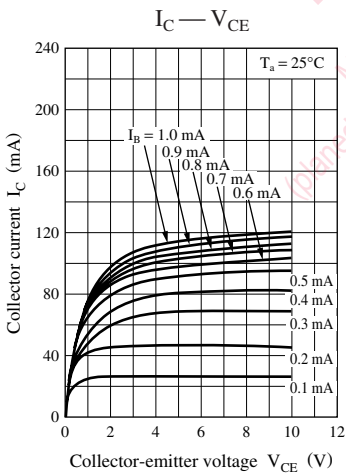
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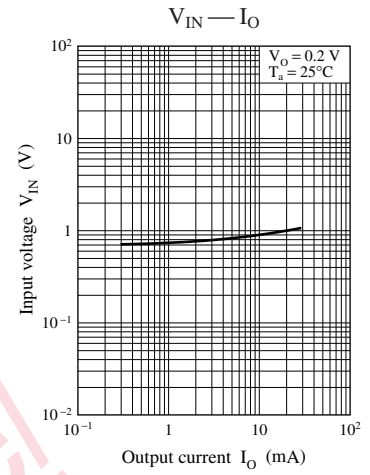
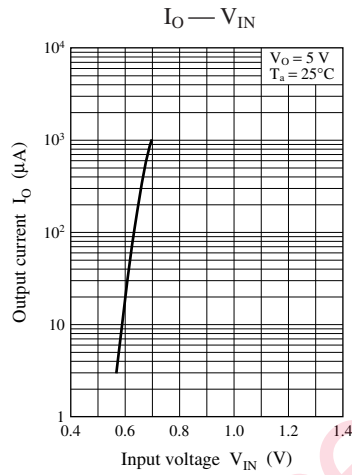
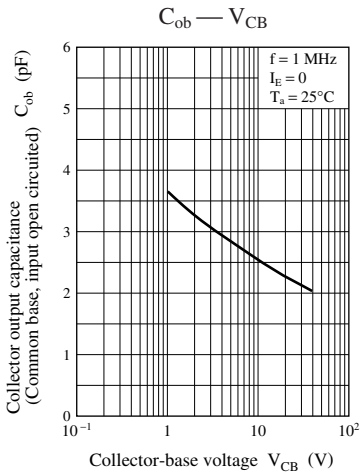


Characteristics charts of UNR5218

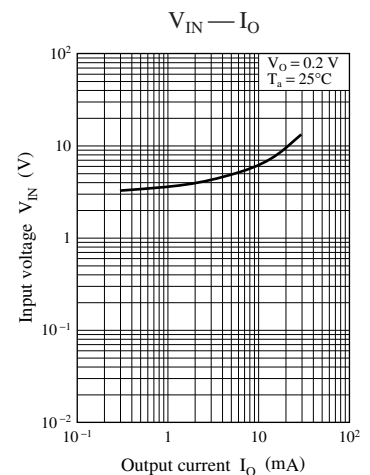
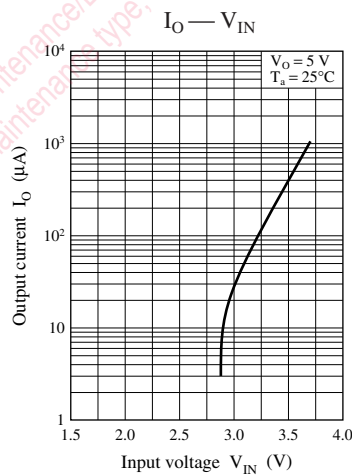
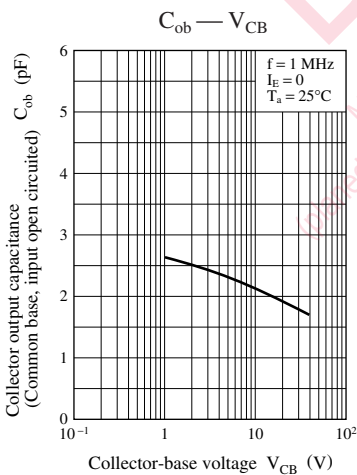
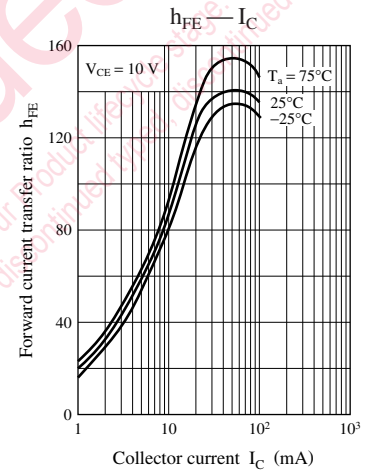
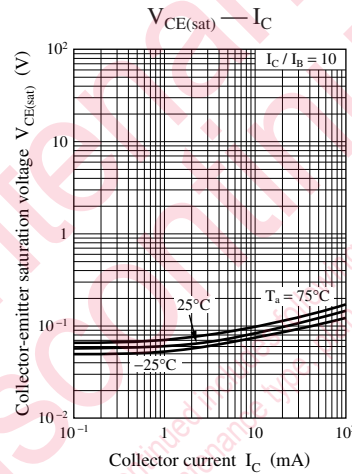
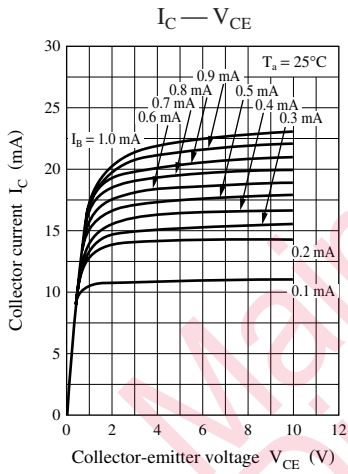


Characteristics charts of UNR5219

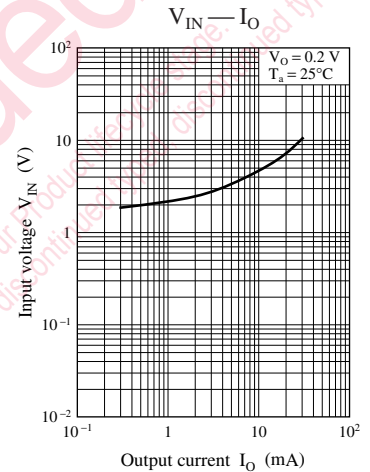
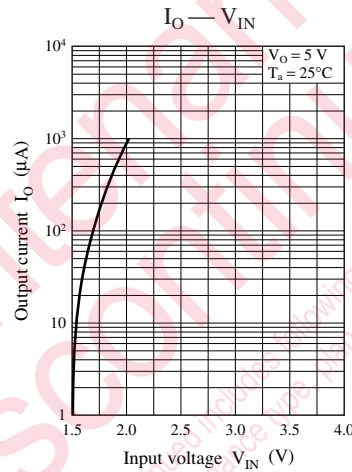
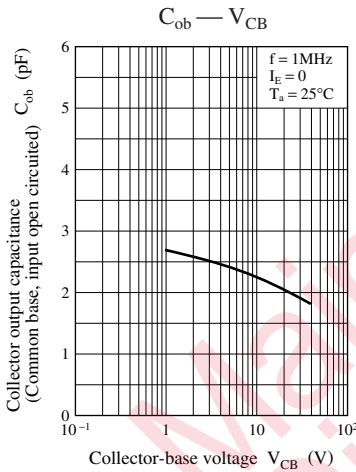
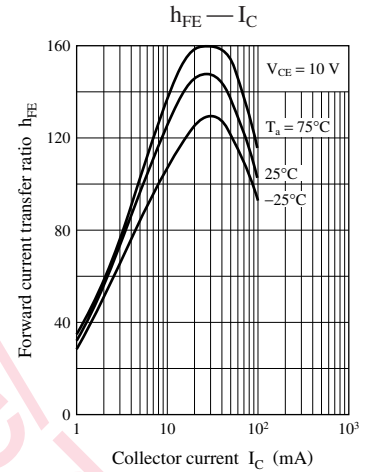
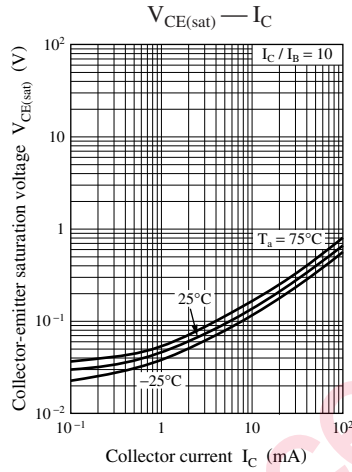
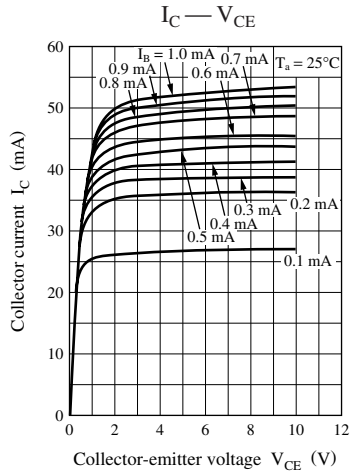




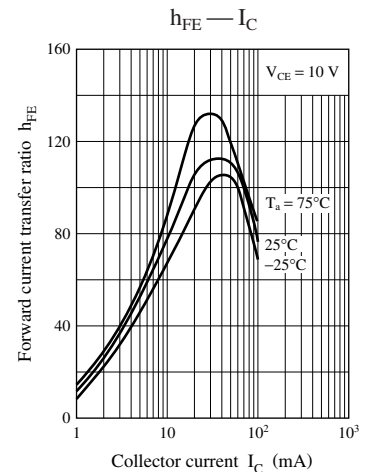
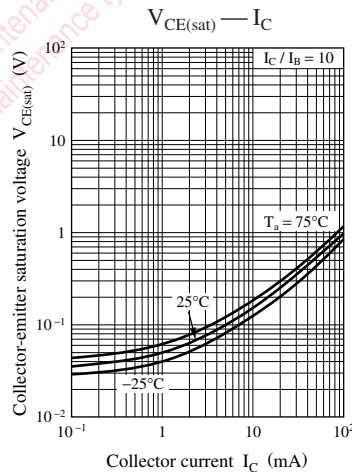
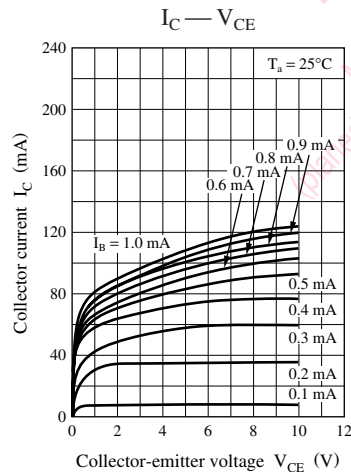
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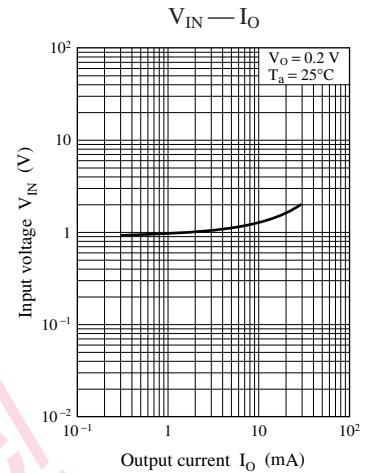
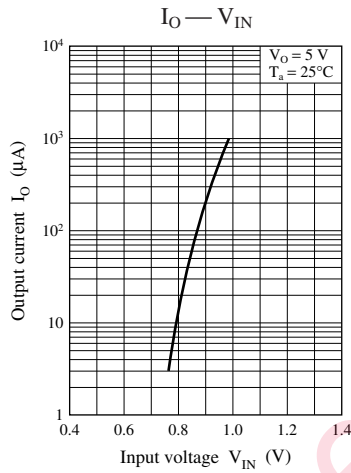
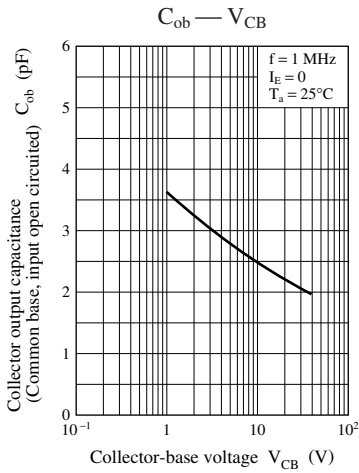


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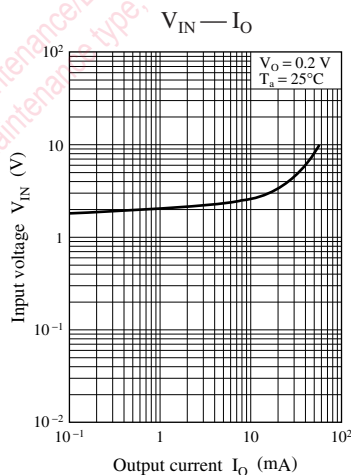
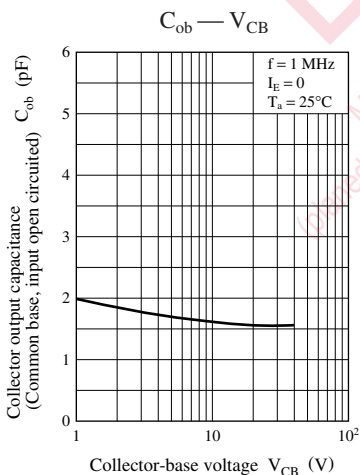
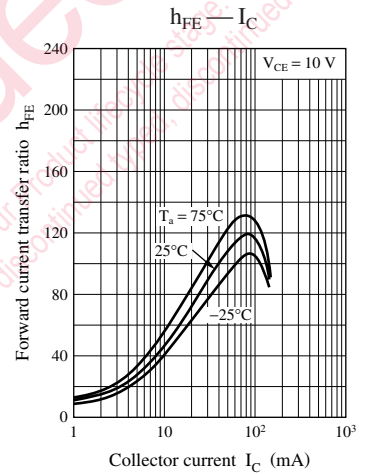
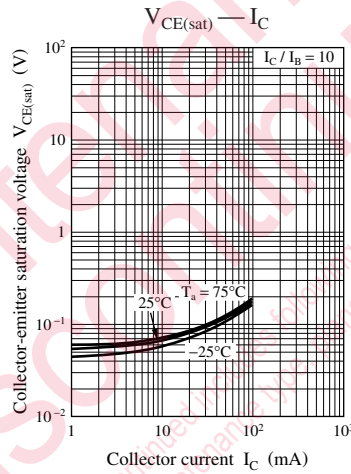
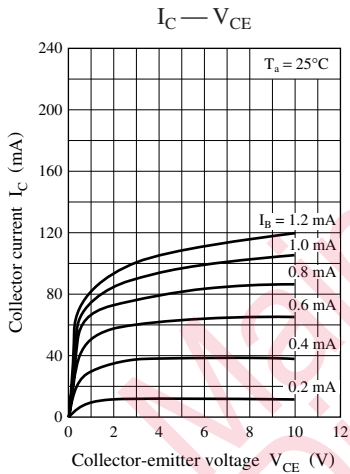


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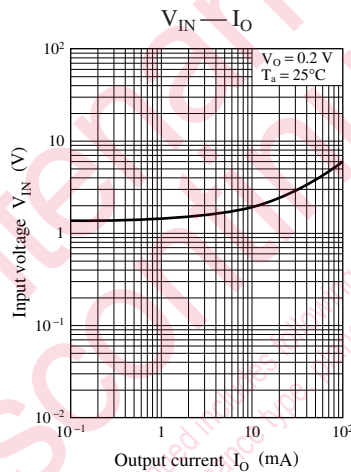
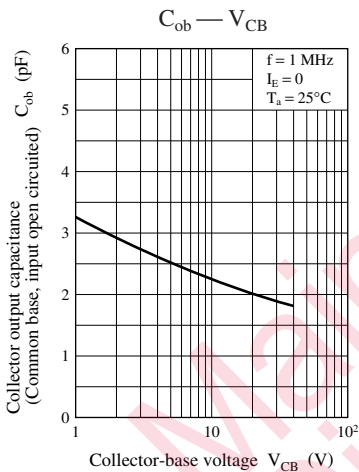
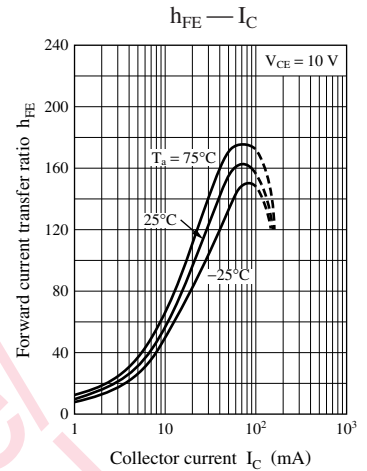
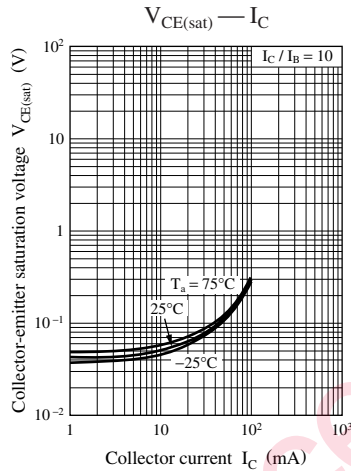
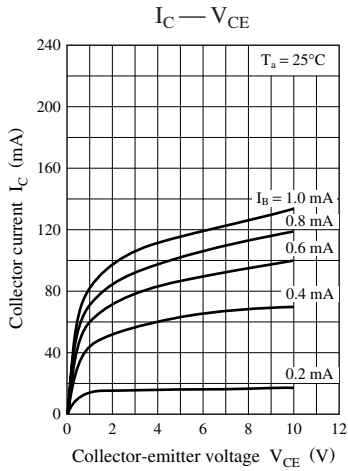




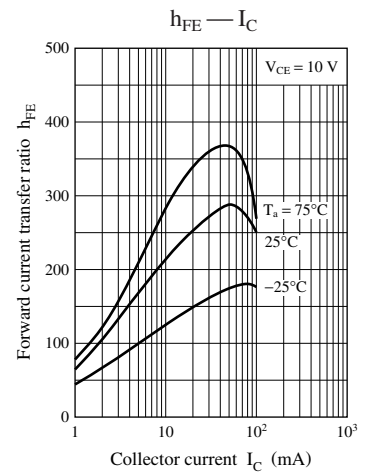
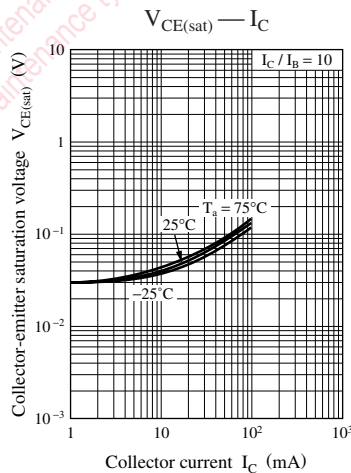
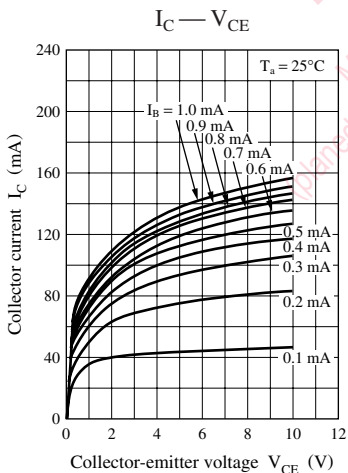
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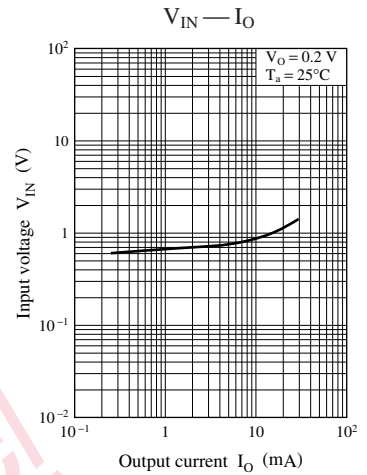
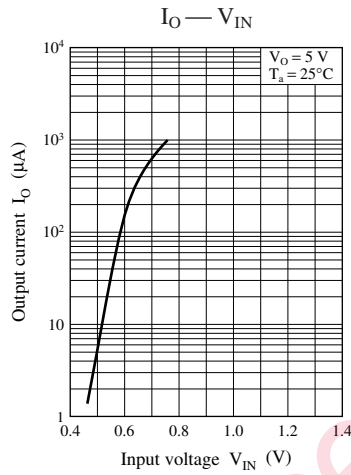
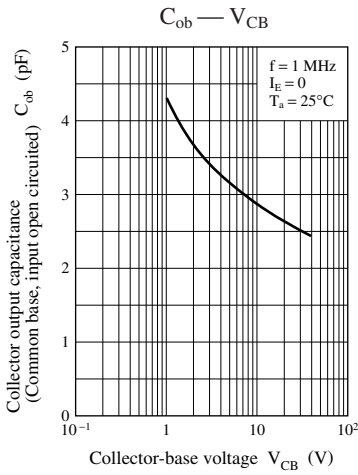


Characteristics charts of UNR521L

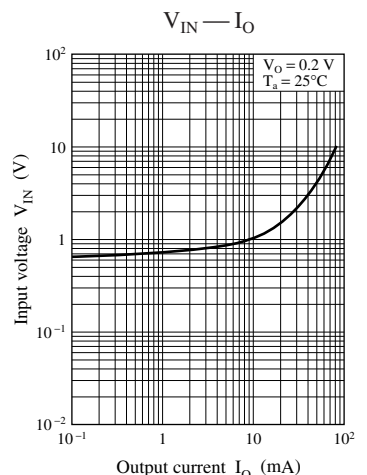
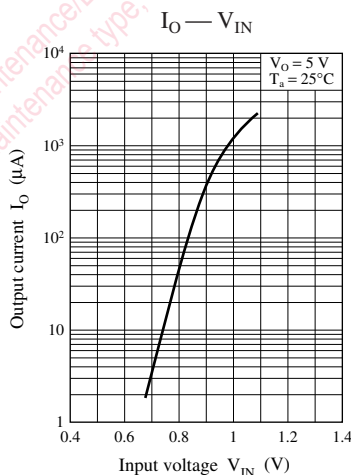
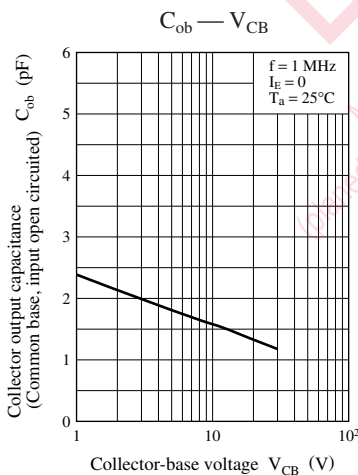
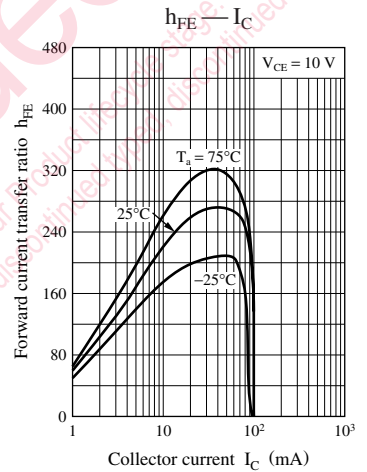
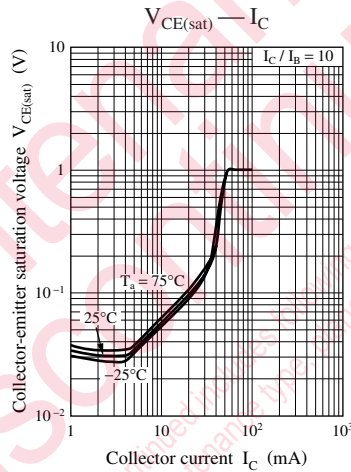
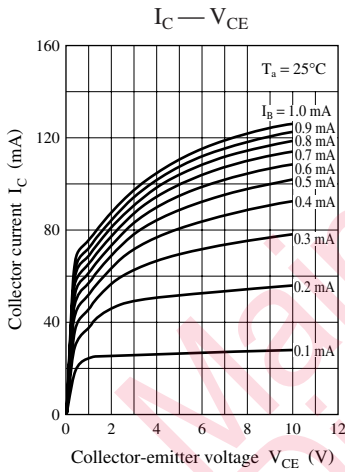


Characteristics charts of UNR521M

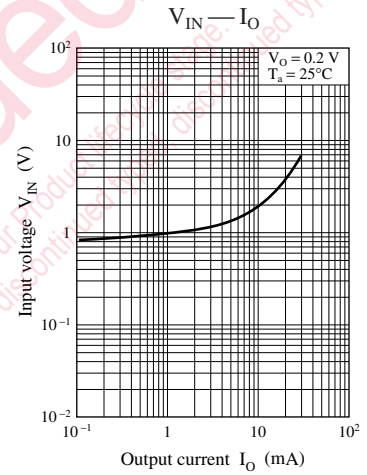
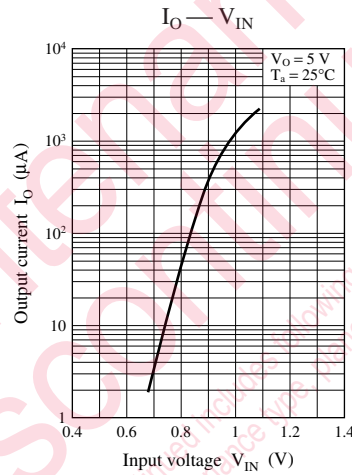
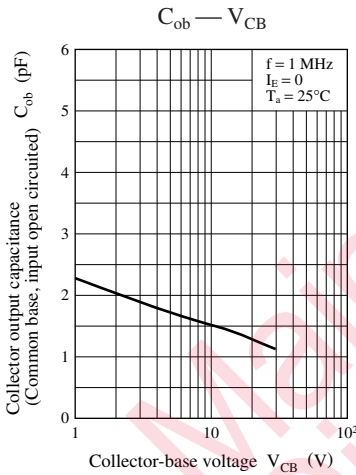
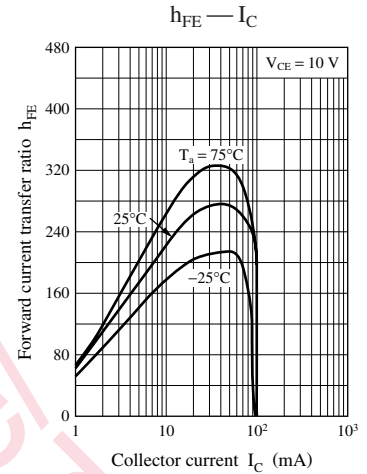
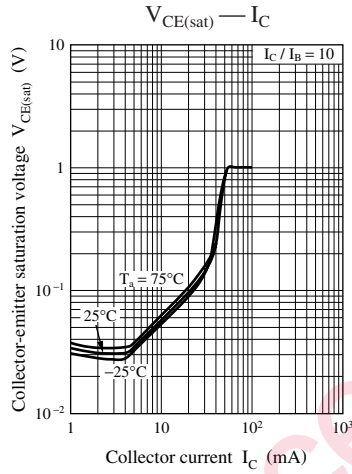
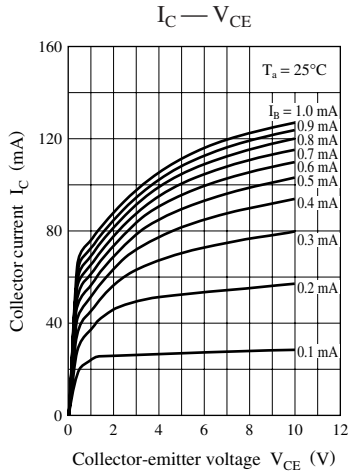




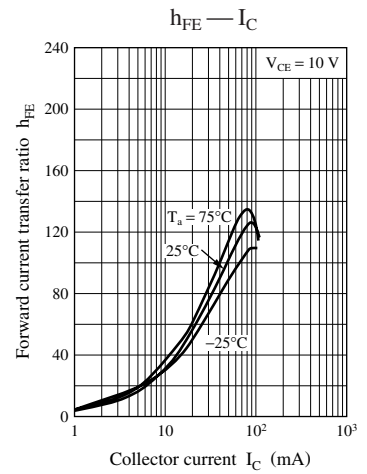
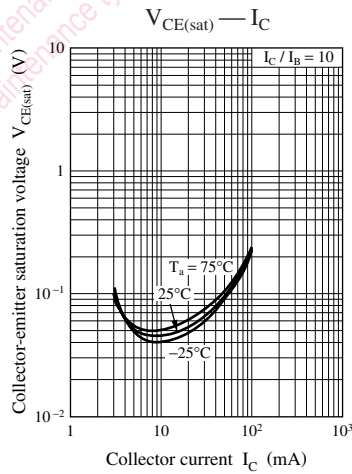
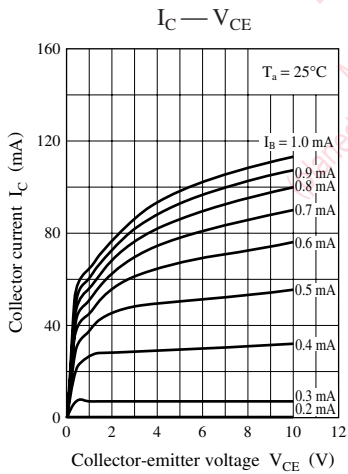
Characteristics charts of UNR521N

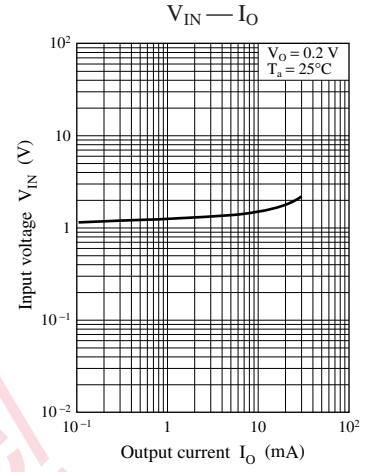
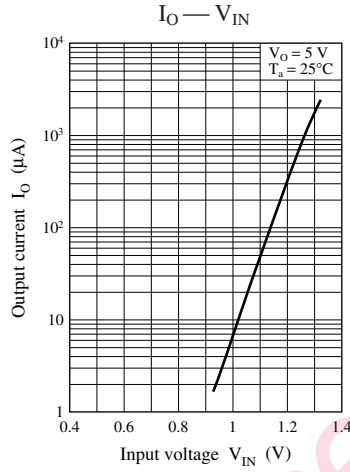
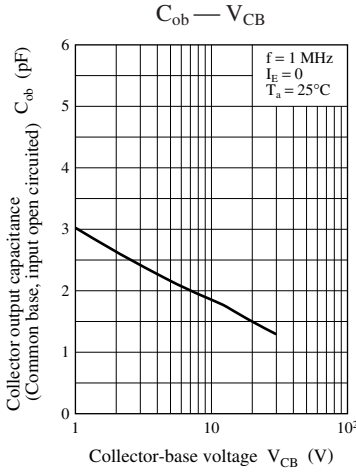


Characteristics charts of UNR521T

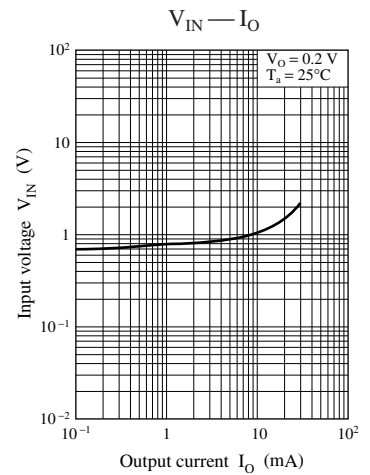
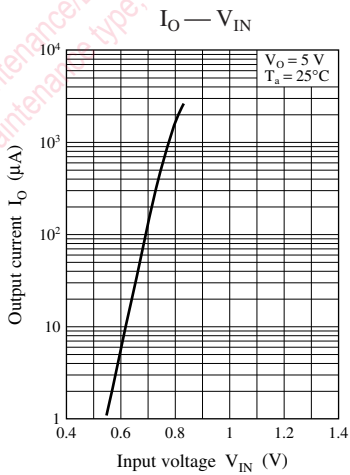
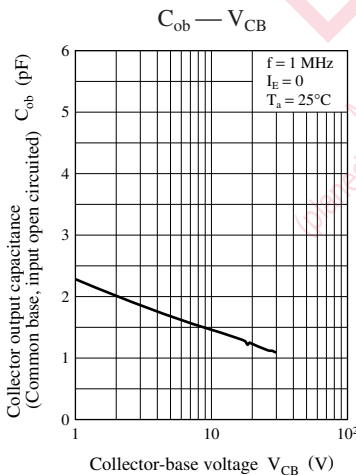
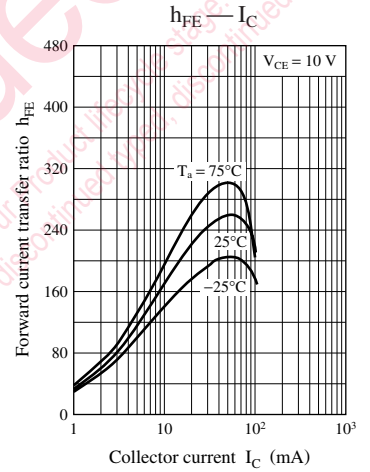
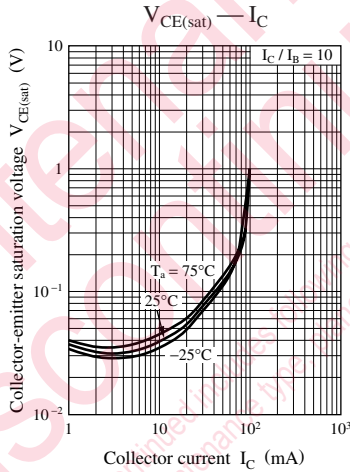
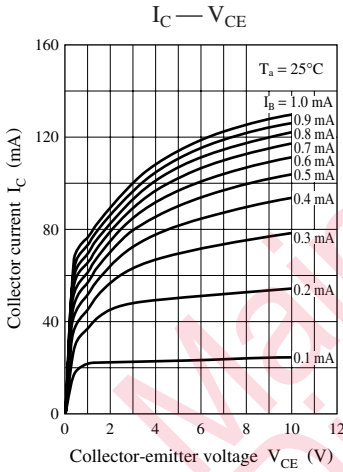


Characteristics charts of UNR521V





Characteristics charts of UNR521Z



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